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(54) **SUBDURAL ELECTRO-OPTICAL SENSOR**

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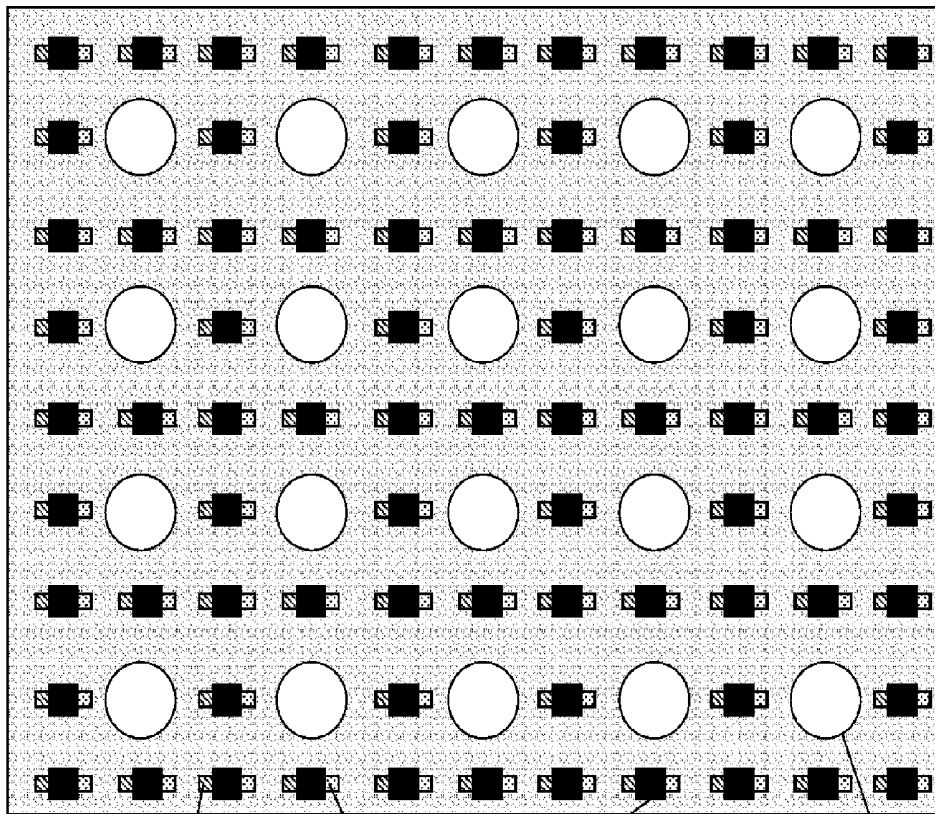
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(57) **ABSTRACT**

A subdural electro-optical sensor system may include a substrate to which is attached an array of electrodes, light emitters, and light detectors. The sensor system may be sufficiently thin, flexible, sterile and biocompatible to be positioned subdurally.

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Thin Board **Light Source 1** **Light Source 2** **Light Detector** **Electrode**

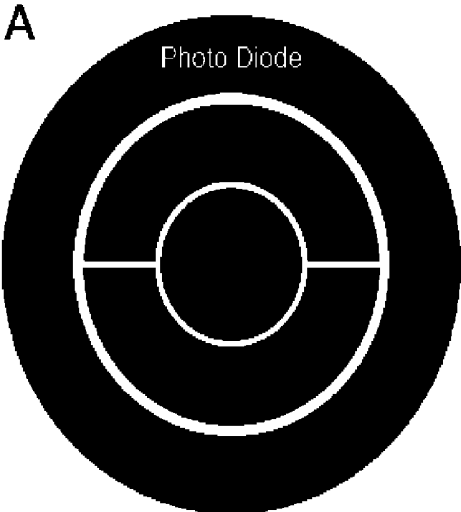


FIG. 3A

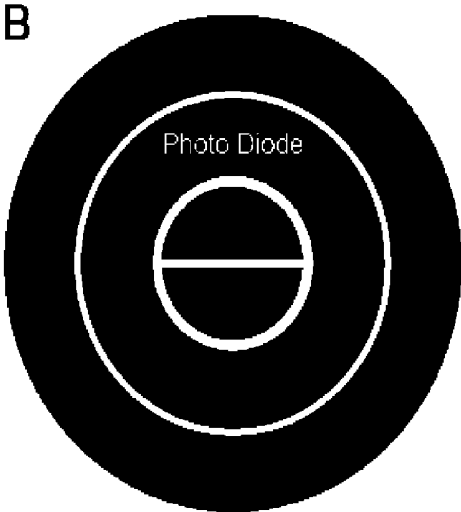


FIG. 3B

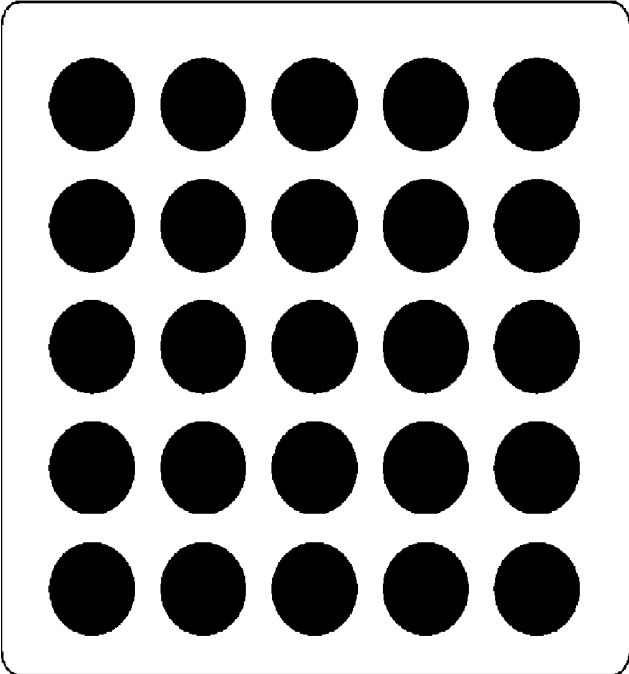


FIG. 4

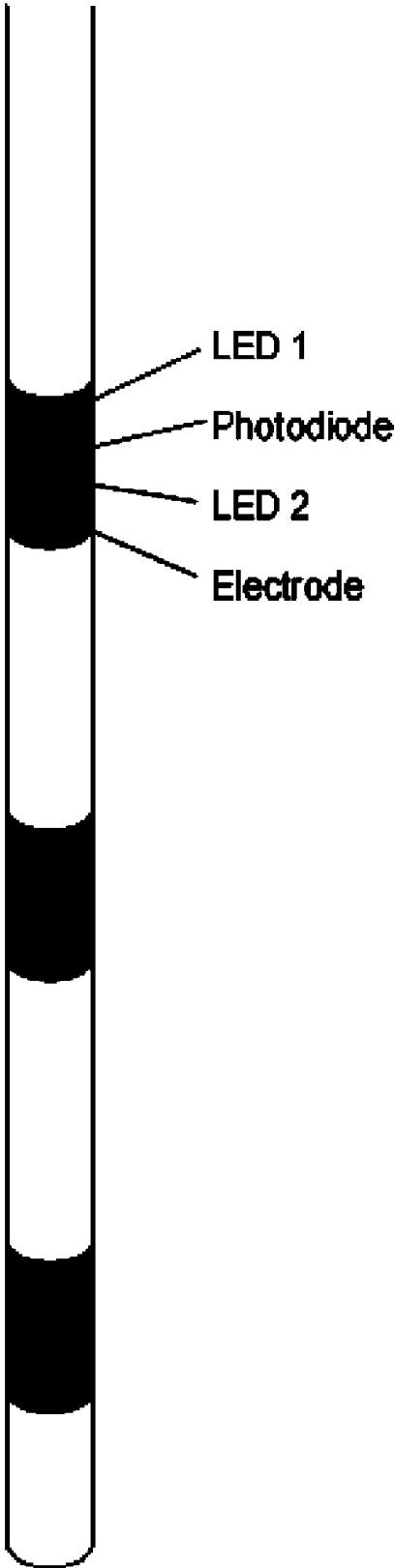


FIG. 5

SUBDURAL ELECTRO-OPTICAL SENSOR

CROSS-REFERENCE TO RELATED APPLICATION

[0001] This application claims the benefit of U.S. Provisional Application No. 60/915,864, filed May 3, 2007, which is hereby incorporated herein by reference.

SUMMARY

[0002] Disclosed are systems and methods for monitoring brain activity, blood flow, and other processes in a patient using an intracranial sensor.

[0003] A sensor for intracranial monitoring may include a thin probe having multiple light sources, multiple light sensors, and multiple electrodes disposed therein or thereon. The probe may have a planar configuration. The probe may have an elongate configuration. The light sources may be infrared light sources. The light sensors may be sensitive to infrared light. The sensor may be implantable intracranially, superficial to the pia mater. The sensor may be implantable between the dura mater and the Arachnoid mater. The sensor may be positioned over a wide variety of brain regions.

BRIEF DESCRIPTION OF THE DRAWINGS

[0004] FIG. 1 schematically depicts an exemplary embodiment of a planar intracranial electro-optical sensor.

[0005] FIG. 2 schematically depicts an exemplary embodiment of an elongate intracranial electro-optical sensor.

[0006] FIGS. 3A-3B schematically depict exemplary embodiments of integrated electro-optical sensors.

[0007] FIG. 4 schematically depicts an exemplary embodiment of a planar intracranial electro-optical sensor using integrated sensors of FIGS. 3A and/or 3B.

[0008] FIG. 5 schematically depicts another exemplary embodiment of an elongate intracranial electro-optical sensor.

DETAILED DESCRIPTION

1. Device Configuration

[0009] A. Pad Configuration

[0010] The electrodes and imaging components are arranged approximately in a plane (see FIG. 1 for a regular grid-like arrangement). The components may be embedded in a pad that is thin, flexible, sterile, and biocompatible to allow intracranial implantation, preferentially between the pia mater and the cranium. The pad can be of any shape, such as square, rectangular, circular, etc. The pad may have a thickness of about 300 micrometers or more; the electrical components attached to the pad may have a thick of about 500 micrometers or more; the total device thickness can be about 8000 micrometers or more, such as about 1000 micrometers. Pads such as those used in strip- and grid electrodes for long-term monitoring made by Ad-Tech Medical Instrument Corporation may be employed. Inter-electrode spacing may be in the range of 1 mm to 20 mm, or in the range of 5 mm to 15 mm, or in the range of 10 mm to 15 mm, or about 10 mm, or exactly 10 mm. Imaging components may be interspersed among the electrodes, as shown in FIG. 5.

[0011] Alternatively, integrated electro-optical sensors may be employed. Examples are schematically shown in FIGS. 3A and 3B. Such integrated sensors may be arrayed on

a pad, as shown in FIG. 4. Inter-sensor spacing may be as described above for inter-electrode spacing.

[0012] B. Probe Configuration

[0013] The electrodes and imaging components are arranged along an elongate probe (exemplary embodiments schematically depicted in FIGS. 2 and 5). The probe is thin and sterile to allow minimally traumatic brain implantation, or may be a component of a deep brain stimulation unit. For example, the probe may have an outer diameter of up to 5 millimeters, up to 4 millimeters, up to 3 millimeters, up to 2 millimeters, and/or up to 1 millimeter, and/or in the range of about 1 millimeter and 2 millimeters; and a length suitable for reaching structures of interest within the brain. For example, the length may be in the range of about 5 centimeters to about 20 centimeters, about 5 centimeters to about 15 centimeters, about 10 centimeters to about 15 centimeters, and/or about 10 centimeters to about 13 centimeters. The electrodes may be provided as ring electrodes on the surface of the probe.

[0014] In some configurations, several small boards may be implanted at various locations. Each board may be delivered through a small craniotomy or another approach. Using several small boards instead of one larger board may eliminate the need for a large craniotomy to accommodate a larger board.

[0015] C. Localization of Implantation

[0016] i. The pad conformation of the device is implanted between the pia mater and the cranium, preferentially between the dura and arachnoid layers. The device may be intracranially implanted superficial to the pia mater. The device may be intracranially implanted deep to the dura mater. The device may be implanted in the subdural space. The device may be implanted in the subarachnoid space.

[0017] ii. A probe device could be implanted intracranially, in any area of interest.

[0018] For instance, a probe may be placed to monitor deep cerebral structures (i.e. amygdala, hippocampus and cingulum) which are characteristically involved in many medically refractory partial epilepsies.

[0019] Further, the probe could be implanted to measure brain activity in the substantia nigra to provide closed loop monitoring for deep brain stimulating device to treat a wide variety of disorders, such as Parkinson's, Tourette Syndrome, and/or other movement disorders. The probe could be implanted to monitor brain activity for detecting and/or treating epilepsy; obsessive-compulsive disorder, depression, and other psychiatric disorders; phantom limb pain, cluster headaches, and other pain disorders; traumatic brain injury; and stroke.

2. Components

[0020] A. Electrodes

[0021] The electrodes are designed for monitoring cortical electrical activity. The electrodes will be made from a substance that records electrical activity in the brain such as platinum, stainless steel or titanium, which is also suitable for implantation. For subdural implantation, thin disc-shaped electrodes will be used, with a diameter of 0.1-10 mm. For intracranial depth implantation, electrodes will be implanted along the length of a soft long, narrow tube, each electrode having a diameter of 0.1-10 mm.

[0022] B. EMR Sources

[0023] The electromagnetic radiation will be directly obtained from implantable LED and/or laser chips, or guided by optical fibers from external electromagnetic sources. For

the pad configuration, the implantable EMR sources are thin (less than 0.5 mm) LED or laser chips, with an illumination range from 300-2000 nm. For a probe device, the EMR sources are either thin LED/laser chip or implantable optical fibers, which guide illumination from external illumination source.

[0024] C. Detectors

[0025] The optical signal will be recorded with photodiodes or CCD cameras. These devices convert optical signal into electrical signal, which can be simultaneously recorded with the neuronal activity. The thickness of the detectors is less than 0.5 mm and they are suitable for implantation in the subdural space.

[0026] When photodiodes are used, they may be coupled to an amplifier to generate signals indicative of detected light. An amplifier, such as used in WuTech Instruments' diode array systems may be used.

[0027] Light sources and detectors can be integrated into the light emitter/detectors. An integrated light emitter/detector may include one or more emitters and one or more detectors. For example, an integrated light emitter/detector may include one emitter and one detector, two emitters and one detector, one emitter and two detectors, two emitters and two detectors, etc. Integrated light emitter/detectors having at least two light emitters may be used to obtain spatially registered optical image maps using multiple wavelengths.

3. System

[0028] The cortex can be illuminated with different wavelengths sequentially, controlled by a computer. Alternatively, the illumination can be with white light and filters can be placed over the detectors to record at different wavelengths. The optical/electrical signal from each detector/electrode is amplified with its own parallel amplifier. The optical and electrical signals are simultaneously recorded with a computer for data analysis. The electrical activity maps and optical imaging maps will be generated by the software.

4. Optical Imaging Methods

[0029] The device could use at least two different types of Optical Imaging which would likely require different optical components:

[0030] A. ORIS (Optical Recording of Intrinsic Signal)

[0031] Optical signals detected at specific imaging wavelengths that map the brain according to perfusion-related and metabolic signals that reflect neuronal activity, including hemoglobin concentration and oxygenation changes, cytochrome oxidation changes, and light scattering caused by altered blood volume, blood flow, and cell swelling. For example, imaging at 610 nm emphasizes deoxyhemoglobin concentration changes, and imaging at 570 nm detects blood volume changes. ORIS have a tissue penetration of several hundreds of micrometers to a few millimeters. Components: LED, photodiodes. A light source may "selectively" emit light of a wavelength, meaning that the source emits light of the identified wavelength, optionally light in a narrow band (such as 1, 2, 5, or 10 nm in either direction) around the identified wavelength, and little or no light beyond the narrow band.

[0032] B. DOT (Diffused Optical Tomography)

[0033] Recently developed technology which can perform continuous 3D imaging. This technique uses near-infrared (NIR) light, to detect not only absorption but also light scattering properties of biological tissues that correlate with neu-

ronal activity. The tissue penetration of this imaging technology is up to 4 cm. Components: laserchips or fiber optics, photodiodes.

5. Methods

[0034] The device would be used for monitoring of brain function in patients prior to an invasive surgical treatment such as ablation of epileptic foci in drug refractory patients, or to monitor brain swelling in patients who have suffered a stroke or brain trauma, who may need a craniectomy to relieve pressure.

[0035] The device can be implanted in patients with epilepsy to help determine the location of the seizure onset and then to monitor brain functions such as motor, sensory, visual or language cortex. In addition, this device could be implanted in patients with head trauma to monitor blood flow and oxygenation. It could be implanted in patients with ischemia to monitor blood flow and oxygenation and neuronal activity.

[0036] The device could also serve as a sensing system as part of closed loop deep brain stimulation system in indications such as Parkinson's, Alzheimer's, or as stimulation to change a state of consciousness.

[0037] The device may be used to predict and/or detect onset of conditions that are preceded by optically-detectable changes. For example, hemodynamic changes that presage epileptic seizures may be detected prior to seizure onset (Zhao et al., "Focal increases in perfusion and decreases in hemoglobin oxygenation precede seizure onset in spontaneous human epilepsy." *Epilepsia* 48:2059-67 (Nov. 2007), hereby incorporated herein by reference). Such prediction/detection may be used, e.g., to warn the patient, warn a care provider, or administer a treatment. The device may include, or be functionally connected to, an electrical stimulator, such as a surface stimulator or deep brain stimulator, to administer electrical stimulation to the subject's brain to abate (i.e., stop or lessen) the seizure or other condition.

We claim:

1. A subdural electro-optical sensor system comprising: a substrate to which is attached an array of electrodes, light emitters, and light detectors; wherein the sensor system is sufficiently thin, flexible, sterile and biocompatible to be positioned subdurally.
2. The sensor system of claim 1, wherein the array comprises electrodes alternating with integrated light emitter-sensors.
3. The sensor system of claim 2, wherein each integrated light emitter-sensor comprises one light detector and two light emitters.
4. The sensor system of claim 3, wherein the two light emitters selectively emit light at 570 nm and at 610 nm, respectively.
5. The sensor system of claim 1, wherein the array comprises multiple integrated sensors, each integrated sensor comprising an electrode, two light emitters, and a light detector.
6. The sensor system of claim 1, further comprising a processor coupled to the electrodes and light detectors so as to receive signals from them indicative of light detected by the light detectors and voltages measured by the electrodes.
7. The sensor system of claim 6, further comprising a responsive element so coupled to the processor as to initiate an action in response to the received signals.

8. The sensor system of claim 7, wherein the responsive element comprises a brain stimulator.

9. The sensor system of claim 1, wherein the light detectors are photodiodes, and the system further comprises an amplifier coupled to the photodiodes.

10. A method of monitoring a property of a subdural structure in a subject, comprising:

implanting the sensor system of claim 1 subdurally and superficial to the subject's pia mater;

emitting light from at least one light emitter upon the subdural structure;

detecting light emitted from the subdural structure at the light sensor;

measuring a voltage between an electrode and a reference potential or a second electrode; and

generating one or more output signals indicative of the detected light and the measured voltage.

11. The method of claim 10, wherein at least one light emitter emits light selectively at 570 nm, at least one light emitter emits light selectively at 610 nm, and the method further comprises detecting a hemodynamic change from the detected emitted light.

12. The method of claim 10, further comprising an electrical stimulator, and the method comprises stimulating the subject's brain using the electrical stimulator if at least one of the detected light and the measured voltage indicate the need for brain stimulation.

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专利名称(译)	硬膜下光电传感器		
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摘要(译)

硬膜下电光传感器系统可包括基板, 电极阵列, 光发射器和光检测器附接到基板。传感器系统可以足够薄, 柔韧, 无菌和生物相容以便在硬顶下定位。

